# Issues pertaining to D 'yakonov-Perel' spin relaxation in quantum wire channels

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#### A bstract

We elucidate the origin and nature of the D'yakonov-Perel' spin relaxation in a quantum wire structure, showing (analytically) that there are three necessary conditions for it to exist: (i) transport must be multi-channeled, (ii) there must be a Rashba spin orbit interaction in the wire, and (iii) there must also be a D resselhaus spin orbit interaction. Therefore, the only elective way to completely eliminate the D'yakonov-Perel' relaxation in compound sem iconductor channels with structural and bulk inversion asymmetry is to ensure strictly single channeled transport. In view of that, recent proposals in the literature that advocate using multi-channeled quantum wires for spin transistors appear ill-advised.

### 1 Introduction

C oherent spin transport in sem iconductor quantum wires is the basis for interesting spintronic devices such as the Spin Field E ect Transistor (SPINFET) [1]. In this device (and its closely related cousins) a quasi. one-dimensional quantum \wire" (as opposed to a quasitwo-dimensional quantum \well") is preferred as the channel for several reasons. First, one dimensional con nem ent of carriers am eliorates the harm fule ects of ensemble averaging (at a nite tem perature), thereby producing a strong conductance modulation [1]. This is a pre-requisite for any good \transistor" where the conductance of the \on" and \o " states must di er by several orders of magnitude. Second, one-dimensional con nem ent leads to a severe suppression of spin relaxation [2], [3]. As a result, the transistor channel can be made long, which not only relaxes the dem ands on fabrication, but also reduces the threshold voltage for switching the device (the threshold voltage of a SPINFET is inversely proportional to the channel length). This, in turn, reduces the dynamic power dissipation. Of course, increasing the gate length also increases the transit time through the channel. and the switching delay, but the power dissipation is proportional to the square of the threshold voltage and hence inversely proportional to the square of the gate length, while the transit time is linearly proportional to the gate length. As a result, the important gure of merit { the power delay product { scales inversely with the gate length. A reduced power delay product may be ultimately the most signi cant advantage that spintronics has over conventional electronics.

This paper is organized as follows. In the next section, we discuss the D'yakonov-Perel' spin relaxation in a quantum wire structure and derive analytical expressions for the spatial evolution of the average spin of an electron ensemble as a consequence of D'yakonov-Perel' relaxation. The derived expressions are perfectly general and are valid in the presence of arbitrary driving electric elds, momentum random izing collisions and inter-subband scattering. B ased on these expressions, we derive the necessary and su cient conditions

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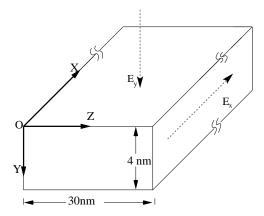


Figure 1: Geometry of the quantum wire. Here  $E_x$  is the longitudinal electric eld that induces current ow. The transverse electric eld  $E_y$  induces R ashba spin-orbit coupling.

for the D'yakonov-Perel' spin relaxation to exist in a quantum wire. Finally, we conclude by stressing the importance of ensuring single channeled transport in spintronic devices in order to elim inate the D'yakonov-Perel' relaxation.

## 2 D'yakonov-Perel' relaxation

The D'yakonov-Perel'spin relaxation is caused by momentum -dependent spin-orbit interactions that originate from bulk inversion asymmetry (giving rise to a D resselhaus interaction) and structural inversion asymmetry (giving rise to a Rashba interaction). In this section, we will analytically derive the temporal and spatial evolution of the average spin of an ensemble of electrons in a quantum wire in the presence of these spin orbit interactions. This will elucidate the origin of the D'yakonov-Perel' relaxation in a quasione-dimensional structure, and identify pathways to eliminate it.

Consider the quantum wire structure shown in Figure 1. A transverse electric eld  $E_y \circ$  is applied perpendicular to the wire axis ( $\diamond$ ) to induce a structural inversion asymmetry that causes a Rashba spin orbit interaction [4]. This structure min ics the SPINFET [1]. Since materials that have strong Rashba coupling (preferred for SPINFETs) usually also have bulk inversion asymmetry, we will assume that there is also a D resselhaus interaction [5].

Spin evolution in the presence of spin-orbit interaction is treated by the standard spin density matrix [6]

(t) = 
$$\begin{array}{c} \mathbf{""} (t) & \mathbf{"\#} (t) \\ \mathbf{\#"} (t) & \mathbf{\#\#} (t) \end{array}$$
 (1)

which is related to the spin polarization component as  $S_n(t) = Tr[n(t)]$  where n = x, y, z and n-s are Paulispin matrices. This spin density matrix evolves under the in unce of momentum dependent spin orbit coupling H am iltonian H<sub>SO</sub> (K) as

$$(t+t) = \exp - \frac{iH_{SO}(k) t}{2} \qquad (t) \exp - \frac{iH_{SO}(k) t}{2} \qquad (2)$$

The spin-orbit coupling H am iltonian has two m ain components: one due to D resselhaus interaction

$$H_{D}(k) = \sim \sim$$
(3)

and the other due to R ashba interaction, whose strength depends on the transverse electric  $eld E_y$  and is given by

$$\begin{array}{ccc} h & i \\ H_{R}(k) = & \sim & \tilde{k} & \circ \end{array}$$

$$(4)$$

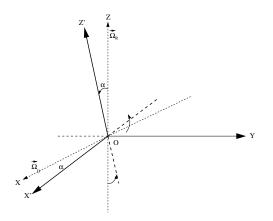


Figure 2: A xis designations

The constants and depend on the material and, in case of , also on the external electric eld  $\mathbf{E}_{\mathbf{y}}$ . In equation (3), ~ is given by ~ =  $_{\mathbf{x}}\mathbf{\hat{x}} + _{\mathbf{y}}\mathbf{\hat{y}} + _{\mathbf{z}}\mathbf{\hat{z}}$  [7] where

$$_{x} = \frac{1}{2} k_{x} f k_{y}^{2} \qquad k_{z}^{2} g + f k_{y}^{2} \qquad k_{z}^{2} g k_{x}$$
 (5)

and  $_y$ ,  $_z$  are obtained by cyclic permutations of  $k_x$ ,  $k_y$  and  $k_z$ . In the quantum wire, electrons can move only along x (the axis of the quantum wire). Hence setting  $k_y = k_z = 0$ , the D resselhaus H am iltonian simpli es to

$$H_{\rm D}(k) = k_{\rm v}^2 \quad k_{\rm z}^2 \quad k_{\rm x \ x}$$
 (6)

where  $k_y^2 = (n = W_y)^2$  and  $k_z^2 = (m = W_z)^2$ . Here m and n are subband indices along  $\hat{z}$  and  $\hat{y}$ , respectively. A lso,  $W_y$  and  $W_z$  are wire dimensions along  $\hat{y}$  and  $\hat{z}$  respectively. Similarly, from equation (4) we can derive the R ashba H am iltonian to be

$$H_{R}(k) = {}_{z}k_{x}$$
<sup>(7)</sup>

From equation (2) we can obtain the temporal evolution of the spin vector as [8], [9]:

$$\frac{\mathrm{d}S}{\mathrm{d}t} = ~~S \tag{8}$$

where the precession vector  $\sim$  has two orthogonal components  $\sim_R$  (k) and  $\sim_D$  (k) due to Rashba and D resselhaus interactions respectively:

$$\widetilde{R}(\mathbf{k}) = \frac{2a_{46}}{2} E_{y} k_{x} \hat{z}$$
(9a)

$$\sim_{D} (k) = \frac{2a_{42}}{\sim} \frac{m}{W_{z}}^{2} \frac{n}{W_{y}}^{2} k_{x} \hat{x}$$
 (9b)

Note that the precession vector  $\sim$  lies in the x z plane (equations (9a) and (9b)). Now we rotate the x z plane about the y axis in a way (Figure 2) such that  $\sim$  becomes coincident with the new z axis. We name this new z axis  $z^0$  and the new x axis  $x^0$ . This requires rotating the x and z axes through an angle in the x z plane as shown in Figure 2. The angle is given by

$$= \tan^{1} \frac{D}{R}$$
(10)

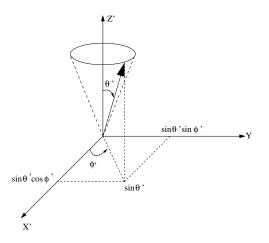


Figure 3: Spin components in x'yz' co-ordinate system

The spin precession equation (8) in the  $x^0yz^0$  coordinate system reads as follows:

$$\frac{dS}{dt} = {}^{\sim} S = det^4 \begin{array}{c} 2 \\ x^0 \\ y \\ z^0 \end{array} \begin{array}{c} 3 \\ z^0 \\ z^0 \end{array}$$

$$(11a)$$

where

$$(t) = \int_{D}^{q} (t) + \int_{R}^{2} (t) = k_{x} (t)$$
 (11b)

and

$$= \frac{2 u^{\#}}{2} (a_{46} E_y)^2 + a_{42}^2 \frac{m}{W_z}^2 \frac{n}{W_y}^{2\#_2}$$
(11c)

From equation (11a) we get

$$\frac{dS_{x^{0}}}{dt} = S_{y}$$
(12a)

$$\frac{dS_{y}}{dt} = S_{x^{0}}$$
(12b)

$$\frac{\mathrm{dS}_{z^0}}{\mathrm{dt}} = 0 \tag{12c}$$

In spherical  $\infty$ -ordinates (Figure 3),  $S_{x^0} = S \sin^{-0} \cos^{-0}$ ,  $S_y = S \sin^{-0} \sin^{-0}$  and  $S_{z^0} = S \cos^{-0} w$  here S is the m agnitude of the spin vector. Substitution of these expressions in equations (12a), (12b) and (12c) yield

$$\frac{d^{0}}{dt} = (t) = k_{x}(t)$$
 (13a)

$$\frac{d^{0}}{dt} = 0$$
(13b)

Solution of Equation (13a) yields

$${}^{0}(t) \qquad {}^{0}(0) = \sum_{k_{x}}^{Z} t^{0} dt^{0}$$

$$= \frac{m}{2} \sum_{0}^{Z} t^{0} v_{x} (t^{0}) dt^{0}$$

$$= \frac{m}{2} \sum_{0}^{Z} t^{0} v_{x} (t^{0}) dt^{0}$$
(14)

where we have assumed a parabolic electron energy dispersion so that the velocity is given by  $v_x$  (t) =  $\sim k_x$  (t)=m (m is the electric mass). Before we proceed to derive the expressions for the spin components as a function of position x, we need to relate the primed quantities to their unprimed counterparts.

$$\cos^{0} = \frac{S \ 2}{jS \ jZ^{0}j} 
= (S_{x}=S) \ z_{x}^{0} + (S_{y}=S) \ z_{y}^{0} + (S_{z}=S) \ z_{z}^{0} 
= (S_{x}=S) \ \sin + (S_{z}=S) \ \cos s 
= \cos \sin \sin + \cos \cos s$$
(15)

where  $z_x^0$  = sin  $% z_y^0$  ,  $z_y^0$  ,  $z_y^0$  ,  $z_z^0$  , z\_z^0 ,  $z_z^0$  , , z\_z^0 , , , , , , , , , , , , ,

$$\sin^{0} = [1 \ A]^{1=2}$$
 (16)

where

$$A = \cos^{2} \circ = \frac{S_{x}}{S} + \frac{S_{z}}{S} + \frac{S_{z}}{S} + \frac{S_{x}S_{z}}{S^{2}} + \frac{S_{x}S_{z}}{S^{2}} \sin 2$$
(17)

The components of S in the original system of coordinates (x;y;z) are then easily obtained from the components in the primed system  $(x^0;y;z^0)$ .

$$S_{x} = S_{x^{0}} \cos + S_{z^{0}} \sin$$

$$= S \sin^{-0} \cos^{-0} \cos + S \cos^{-0} \sin$$

$$S_{y} = S_{y^{0}} = S \sin^{-0} \sin^{-0}$$

$$S_{z} = S_{x^{0}} \sin + S_{z^{0}} \cos$$

$$= S \sin^{-0} \cos^{-0} \sin + S \cos^{-0} \cos$$
(18)

Using equations (15) { (18), we get

$$S_{x} (x) = S_{0} \cos \left[ {}^{0}(x) + {}^{0}(0) \right] \cos + S_{x} (0) \sin^{2} + S_{z} (0) \sin \cos S_{y} (x) = S_{0} \sin \left[ {}^{0}(x) + {}^{0}(0) \right]$$

$$S_{z} (x) = S_{0} \cos \left[ {}^{0}(x) + {}^{0}(0) \right] \sin S_{z} (x) = S_{0} \cos \left[ {}^{0}(x) + {}^{0}(0) \right] \sin S_{z} (x) = S_{x} (0) \sin \cos S_{z} + S_{z} (0) \cos^{2}$$
(19)

where

$$S_{0}^{2} = S^{2} S_{x} (0)^{2} \sin^{2} S_{z} (0)^{2} \cos^{2}$$
  

$$S_{x} (0) S_{z} (0) \sin 2$$
(20)

Let us now consider the situation where electrons are injected into the quantum wire with their spins polarized along the +  $\hat{x}$  direction. In that case,  $^{0}(0) = 0$ ,  $S = S_{x}(0)$  and  $S_{y}(0) = S_{z}(0) = 0$ . The above equation then simpli es to

$$S_{x} (x) = S_{x} (0) \cos^{2} \cos^{0} + \sin^{2} i$$

$$= \frac{S_{x} (0)^{-2} (m; n) + (a_{46}E_{y})^{2} \cos (m; n)x}{^{2} (m; n) + (a_{46}E_{y})^{2}}$$

$$S_{y} (x) = S_{x} (0) \cos \sin^{0} i$$

$$= \frac{a_{46} E_{y} \sin (m; n)x}{^{2} (m; n) + (a_{46}E_{y})^{2}} S_{x} (0)$$

$$S_{z} (x) = S_{x} (0) \sin \cos [1 \cos^{0}] i$$

$$= \frac{2 a_{46} E_{y} (m; n) S_{x} (0)}{^{2} (m; n) + (a_{46}E_{y})^{2}} \sin^{2} \frac{(m; n)x}{2}$$
(21)

where

$$(m;n) = \frac{m^{2} a_{42}}{W_{z}^{2}} \frac{n^{2} a_{42}}{W_{y}^{2}}$$
(22a)

$$(m;n) = \frac{2m}{2} q^{2} (m;n) + (a_{46}E_{y})^{2}$$
(22b)

It is straightforward to verify from equation (21) that

$$S_x (x)^2 + S_y (x)^2 + S_z (x)^2 = 1$$
 (23)

Thus, the magnitude of the spin vector is conserved only for every individual electron. However, when we have an ensemble of electrons, the magnitude of the ensemble averaged spin may decay with distance. This is the D'yakonov-Perel' relaxation. In the next section we investigate when this relaxation exists.

## 3 Necessary conditions for D 'yakonov-Perel' relaxation

#### 3.1 Rashba interaction

We can see in mediately from equation (21) that if there is no Rashba interaction ( $a_{46} = 0$  or,  $E_y = 0$ ), then at all positions x,

$$hS_{x}(x)i = hS_{x}(0)i$$

$$hS_{y}(x)i = hS_{z}(x)i = 0$$
(24)

Therefore,

$$D = E = q = \frac{1}{hS_{x}(x)i^{2} + hS_{y}(x)i^{2} + hS_{z}(x)i^{2}}$$

$$= \frac{hS_{x}(0)i}{D = E}$$

$$= S(0)$$
(25)

= a constant independent of position x

Here the angular brackets h i denote ensemble average over electrons and hS (x) is the ensemble averaged spin vector at position x.

Equation (25) indicates that as along as the carriers are injected with their spins aligned along the axis of the wire, there is no D'yakonov-Perel' relaxation, since the ensemble average spin jS ijdoes not decay at all. Therefore, Rashba interaction is required for the ensemble averaged spin to relax.

#### 3.2 D resselhaus interaction

If there is no D resselhaus interaction  $(a_{42} = 0)$ , then

$$hS_{x}(x)i = S_{x}(0)\cos \frac{2m a_{46}E_{y}}{\sim^{2}} x$$
$$hS_{y}(x)i = S_{x}(0)\sin \frac{2m a_{46}E_{y}}{\sim^{2}} x$$
$$hS_{z}(x)i = 0$$

Therefore,

$$D = E = q = \frac{1}{S(x)} = \frac{1}{hS_{x}(x)i^{2} + hS_{y}(x)i^{2} + hS_{z}(x)i^{2}}$$
$$D = E = S(0)$$

= a constant independent of position x

A gain, we see that the ensemble averaged spin jSijdoes not decay. In this case, the spin oscillates between the x- and y-polarization (the z-polarization remains 0), but the \amplitude" of this oscillation does not decay. Therefore, there can be no D 'yakonov-Perel' relaxation without D resselhaus interaction.

#### 3.3 Multi-channeled transport

If both Rashba and D resselhaus interactions are present, but transport is single channeled, i.e.  $m = m_0$  and  $n = n_0$ , then every electron is in the same subband  $(m_0, n_0)$ . In that case,

$$hS_{x}(x)i^{2} = \frac{S_{x}(0)}{2} + (a_{46} E_{y})^{2} \cos_{0} x}{a_{2}^{2} + (a_{46} E_{y})^{2}} = \frac{a_{46} E_{y} S_{x}(0) \sin_{0} x}{4} = \frac{a_{46} E_{y} S_{x}(0) \sin_{0} x}{a_{2}^{2} + (a_{46} E_{y})^{2}}$$

$$hS_{y}(x)i^{2} = \frac{2 a_{46} O E_{y} S_{x}(0) \sin^{2} (O x=2)}{a_{2}^{2} + (a_{46} E_{y})^{2}}$$

$$(26)$$

where  $_0 = (m_0; n_0)$ , and  $_0 = (m_0; n_0)$ . Once again, it is easy to verify that

$$\frac{q}{hS_{x}(x)i^{2}} + \frac{hS_{y}(x)i^{2}}{hS_{z}(x)i^{2}} + \frac{hS_{z}(x)i^{2}}{hS_{z}(x)i^{2}}$$

$$= \frac{hS_{z}(0)ij}{a \text{ constant independent of position } x}$$

C onsequently, there is no D 'yakonov-P erel' relaxation if transport is single channeled. This is true regardless of whether the electrons are injected into the lowest subband, or any other subband, as long as there is no inter-subband transition.

## 4 W hat is necessary for D 'yakonov-Perel' relaxation?

If transport is multi-channeled, then di erent electrons at position x are in di erent subbands. In that case, the indices n and m are di erent for di erent electrons, so that ensem ble averaging results in

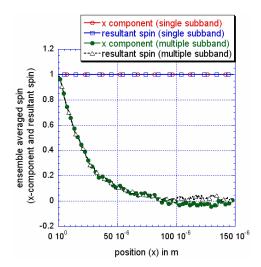


Figure 4: Spin relaxation in a GaAs quantum wire of rectangular cross section 30nm - 4nm. The driving electric eld is 2kV/cm and lattice temperature is 30K. These results are obtained from M onte Carlo sim – ulation described in [2], [3]. Spin does not relax for single channeled (single subband) transport, but does relax for multichanneled transport.

Therefore, multi-channeled transport, in the presence of both R ashba and D resselhaus interaction leads to D 'yakonov-P erel' relaxation. It is important to note that \scattering", or inter-subband transitions are not required for the D 'yakonov-P erel relaxation. Even if every electron remains in the subband in which it was originally injected, there will be a D 'yakonov-P erel' relaxation as a consequence of ensem ble averaging over the electrons. O f course, if there is scattering and inter-subband transitions, then the subband indices (m, n) for every electron becomes a function of position x, in which case the elect of ensem ble averaging is exacerbated and the relaxation will be more rapid. Thus, we have established that three conditions are needed for D 'yakonov-P erel' relaxation: (i) R ashba interaction, (ii) D resselhaus interaction, and (iii) multi-channeled transport.

In Figure 4, we show hS'(x)i as a function of x for two cases: single channeled transport and multichanneled transport. It is evident that the spin does not decay for single channeled transport but does decay for multi-channeled transport.

## 5 Conclusion

In this paper, we have established the origin of the D'yakonov-Perel' spin relaxation in a quantum wire. This relaxation is harm ful form ost spintronic devices (one example is the SPINFET [1]), because it leads to spin random ization. Since optimum materials for SPINFET -type devices (e.g. InAs) usually possess strong R ashba and also some D resselhaus spin orbit interactions, the only eliminate the D'yakonov-Perel' relaxation is to ensure and enforce single channeled transport. There has been recently some proposals that advocate using multi-channeled devices for SPINFET's, along with the claim that they provide better spin control via the use of multiple gates [10]. While we do not believe that spin control is improved by using multiple gates since synchronizing these gates is an additional engineering burden that can only degrade device operation and gate control, it is even more important to understand that multi-channeled transport is harm ful because it dilutes the spin interference eliminate out that multi-channeled transport is harm ful because it dilutes the spin interference eliminate out that multi-channeled transport is harm ful because it dilutes the spin interference eliminate to understand that multi-channeled transport is harm ful because it dilutes the spin interference eliminate to understand the spin spin spin control [1]. Here, we have pointed out an additional motivation to avoid multi-channeled devices: they will sule in from D'yakonov-Perel' relaxation, while the single channeled device will not.

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